TOSHIBA Transistor Silicon PNP Epitaxial Type (PCT Process)

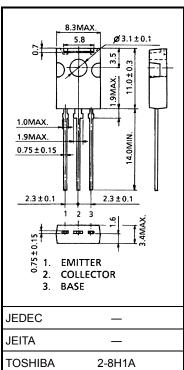
# 2SA1356

#### Audio Power Amplifier Applications

- Low saturation voltage: V<sub>CE</sub> (sat) = -0.32 V (typ.) (I<sub>C</sub> = -500 mA, I<sub>B</sub> = -50 mA)
- High collector power dissipation:  $P_C = 1.2 \text{ W} (Ta = 25^{\circ}C)$
- Complementary to 2SC3419

## Absolute Maximum Ratings (Tc = 25°C)

Characteristics		Symbol	Rating	Unit	
Collector-base voltage		V <sub>CBO</sub>	-40	V	
Collector-emitter voltage		V <sub>CEO</sub>	-40	V	
Emitter-base voltage		V <sub>EBO</sub>	-5	V	
Collector current		Ι <sub>C</sub>	-800	mA	
Base current		Ι <sub>Β</sub>	-80	mA	
Collector power dissipation	Ta = 25°C	Pc	1.2	W	
	Tc = 25°C	FC	5		
Junction temperature		Тј	150	°C	
Storage temperature range		T <sub>stg</sub>	-55 to 150	°C	



Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

Weight: 0.82 g (typ.)

temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

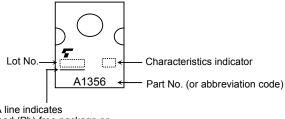
Unit: mm

# **Electrical Characteristics (Tc = 25°C)**

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	$V_{CB} = -40 \text{ V}, \text{ I}_{E} = 0$	_	_	-1.0	μA
Emitter cut-off current	I <sub>EBO</sub>	$V_{EB} = -5 V, I_C = 0$	_	_	-1.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = -10 mA, I <sub>B</sub> = 0	-40	—		V
DC current gain	h <sub>FE (1)</sub> (Note)	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -50 mA	70		240	
	h <sub>FE (2)</sub>	$V_{CE} = -2 V, I_C = -800 mA$	13	50	_	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = -500 mA, I <sub>B</sub> = -50 mA	_	-0.32	-0.8	V
Base-emitter voltage	V <sub>BE</sub>	$V_{CE} = -2 V, I_C = -500 mA$	_	_	-1.3	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = -2 V, I <sub>C</sub> = -0.5 A	50	100	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = −10 V, I <sub>E</sub> = 0, f = 1 MHz		20		pF

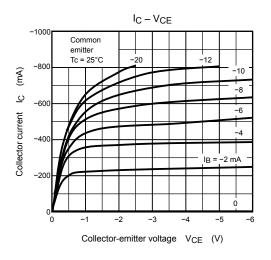
Note: h<sub>FE (1)</sub> classification O: 70 to 140, Y: 120 to 240

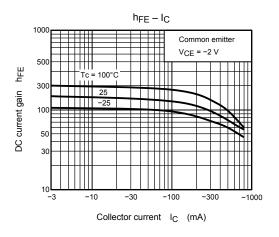
# Marking

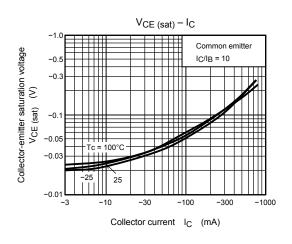


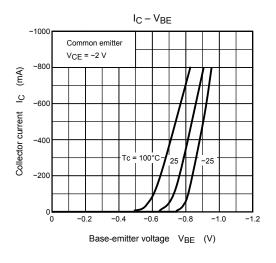
A line indicates lead (Pb)-free package or lead (Pb)-free finish.

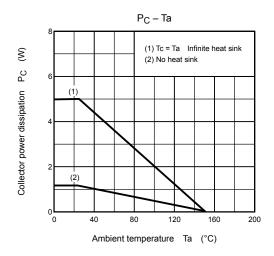
# **TOSHIBA**



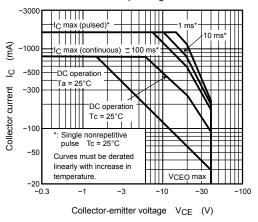








Safe Operating Area



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